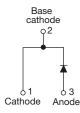
VS-HFA15TB60-M3

Vishay Semiconductors

HEXFRED[®], Ultrafast Soft Recovery Diode, 15 A



www.vishay.com



PRIMARY CHARACTERISTICS					
I _{F(AV)} 15 A					
V _R	600 V				
V _F at I _F	1.2 V				
t _{rr} typ.	23 ns				
T _J max.	150 °C				
Circuit configuration	Single				
Package	2L TO-220AC				

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA15TB60... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 15 A continuous current, the VS-HFA15TB60... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED[®] product line features extremely low values of peak recovery current (IRBM) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA15TB60... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Cathode to anode voltage	V _R		600	V			
Maximum continuous forward current	I _F	T _C = 100 °C	15				
Single pulse forward current	I _{FSM}		150	А			
Maximum repetitive forward current	I _{FRM}		60				
Maximum neuror discinction	D	T _C = 25 °C	74	W			
Maximum power dissipation	PD	T _C = 100 °C	29	vv			
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C			

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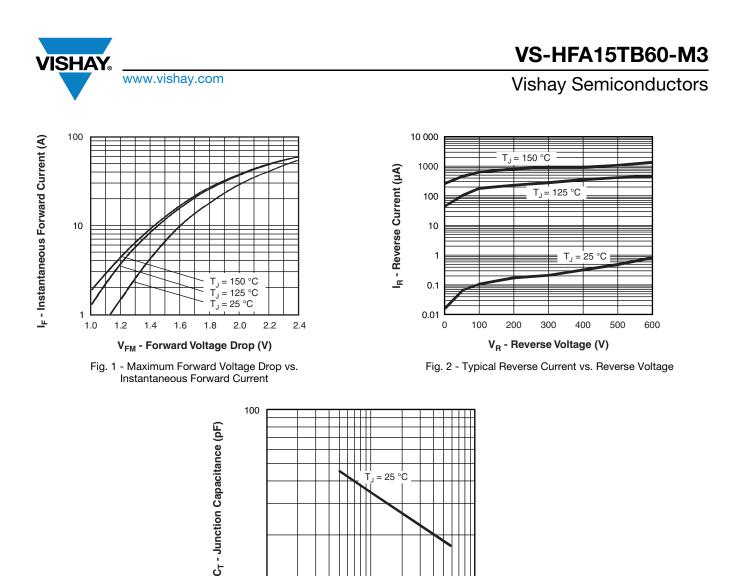
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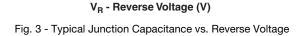
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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-	
		I _F = 15 A		-	1.3	1.7	V
Maximum forward voltage	V_{FM}	I _F = 30 A	See fig. 1	-	1.5	2.0	
		I _F = 15 A, T _J = 125 °C		-	1.2	1.6	
Maximum reverse		$V_{R} = V_{R}$ rated	See fig. 2	-	1.0	10	
leakage current	I _{RM}	T_J = 125 °C, V_R = 0.8 x V_R rated	See lig. 2	-	400	1000	μA
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	25	50	pF
Series inductance	L _S	Measured lead to lead 5 mm from p	ackage body	-	8.0	-	nH

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ di}_F/\text{dt} = 200$	A/µs, V _R = 30 V	-	19	-		
Reverse recovery time See fig. 5	t _{rr1}	T _J = 25 °C		-	42	60	ns A nC	
000 lig. 0	t _{rr2}	T _J = 125 °C	I _F = 15 A di _F /dt = 200 A/μs V _R = 200 V	-	74	120		
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	4.0	6.0		
See fig. 6	I _{RRM2}	T _J = 125 °C		-	6.5	10		
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	84	180		
See fig. 7	Q _{rr2}	T _J = 125 °C		-	241	600		
Peak rate of fall of recovery current during t _b See fig. 8	di _{(rec)M} /dt1	T _J = 25 °C		-	188	-	A/µs	
	di _{(rec)M} /dt2	T _J = 125 °C		-	160	-		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	1.7	K/W
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount -		-	80	r∨ VV
Waight			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style 2L TO-220AC HFA15TB60				

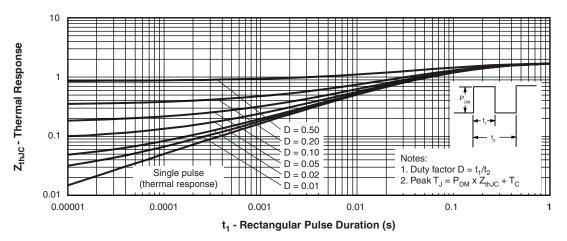




100

1000

10 L 10







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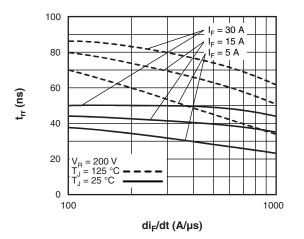


Fig. 5 - Typical Reverse Recovery Time vs. di_F/dt

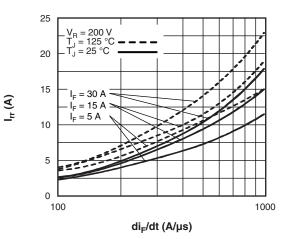
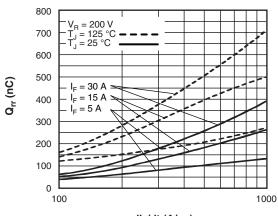


Fig. 6 - Typical Recovery Current vs. di_F/dt







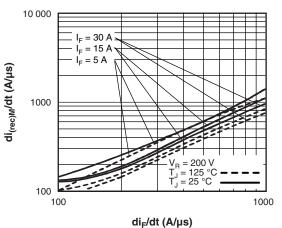




Fig. 8 - Typical di_{(rec)M}/dt vs. di_F/dt

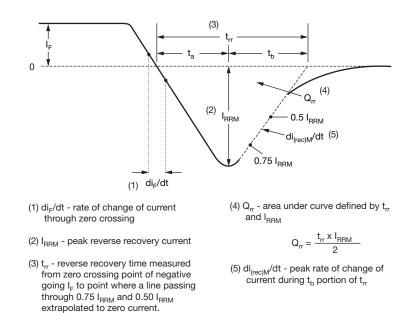


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	VS-	HF	А	15	тв	60	-M3
		2	3	4	5	6	7
	1 -		-	niconduc	ctors pro	oduct	
	2 -		KFRED [®]				
	4 -			ng (15 =	= 15 A)		
	5 -		kage:				
	6 -	. –		-220AC ng (60 =		I	
	7 -		•	ntal digit			
		-M3	= halog	gen-free	, RoHS-	complia	ant, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	PACKAGING DESCRIPTION						
VS-HFA15TB60-M3	50	1000	Antistatic plastic tube				

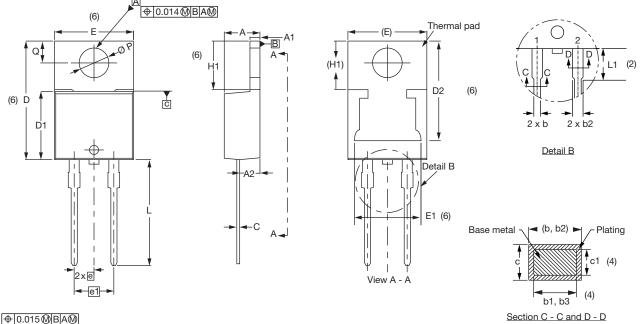
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96156				
Part marking information	www.vishay.com/doc?95391				

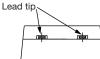


Vishay Semiconductors

2L TO-220AC

DIMENSIONS in millimeters and inches





SYMBOL	MILLIN	MILLIMETERS		INCHES		
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.50	2.92	0.098	0.115		
b	0.69	1.01	0.027	0.040		
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4	
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.35	0.585	0.604	3	
D1	8.38	9.02	0.330	0.355		

Conforms to JEDEC[®] outline TO-220AC

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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